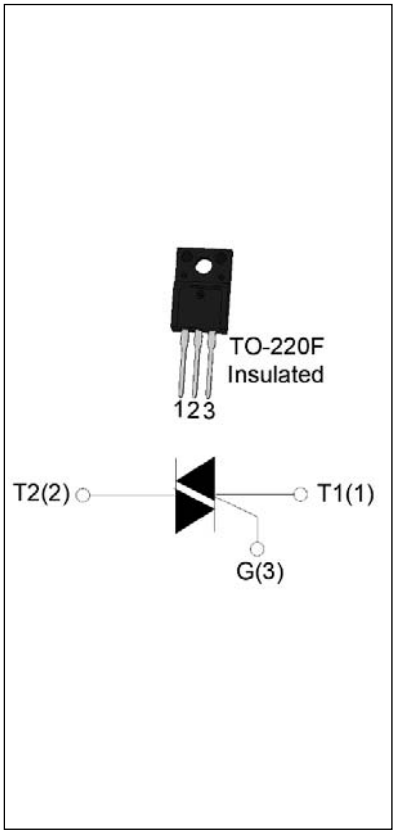
JST06F-600BW 6A TRIAC

Rev.A.1.1

DESCRIPTION:

The JST06F-600BW triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. JST06F-600BW snubberless triac is especially recommended for use on inductive loads. By using an external plastic package, JST06F-600BW provides a rated insulation voltage of 2000 VRMS, complying with UL standards (File ref: E252906). Package TO-220F is RoHS compliant.



MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	6	A
V_{DRM} /V_{RRM}	600	V
$I_{GT\ I/II/III}$	50/50/50	mA

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T_{stg}	-40-150	℃
Operating junction temperature range	T_j	-40-125	℃
Repetitive peak off-state voltage (T_j=25℃)	V_{DRM}	600	V
Repetitive peak reverse voltage (T_j=25℃)	V_{RRM}	600	V
RMS on-state current (T_C≤98℃)	$I_{T(RMS)}$	6	A
Non repetitive surge peak on-state current (full cycle , t_p=20ms , T_j=25℃)	I_{TSM}	65	A
Non repetitive surge peak on-state current (full cycle , t_p=16.6ms , T_j=25℃)		72	
I^2t value for fusing (t_p=10ms , T_j=25℃)	I^2t	21	A^2s
Critical rate of rise of on-state current (I_G=2×I_{GT} , f=100Hz , T_j=125℃)	dI/dt	100	A/μs
Peak gate current (t_p=20μs , T_j=125℃)	I_{GM}	4	A
Average gate power dissipation (T_j=125℃)	$P_{G(AV)}$	0.5	W

Peak gate power	P_{GM}	10	W
Peak pulse voltage (T_j=25℃; non-repetitive,off-state;FIG.7)	V_{pp}	4	kV

ELECTRICAL CHARACTERISTICS (T_j=25℃ unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	V_D =12V R_L =33Ω	Ⅰ-Ⅱ-Ⅲ	MAX.	50	mA
V_{GT}		Ⅰ-Ⅱ-Ⅲ	MAX.	1	V
V_{GD}	V_D =V_{DRM} T_j =125℃ R_L =3.3kΩ	Ⅰ-Ⅱ-Ⅲ	MIN.	0.2	V
I_L	I_G =1.2I_{GT}	Ⅰ-Ⅲ	MAX.	70	mA
		Ⅱ		80	
I_H	I_T =100mA		MAX.	50	mA
dV/dt	V_D=400V Gate Open T_j =125℃		MIN.	2000	V/μs
(dI/dt)c	(dV/dt)c=20V/μs, T_j=125℃		MIN.	8	A/ms
t_{on}	I_G=80mA I_A=400mA I_R=40mA T_j=25℃		TYP.	5	μs
t_{off}				50	

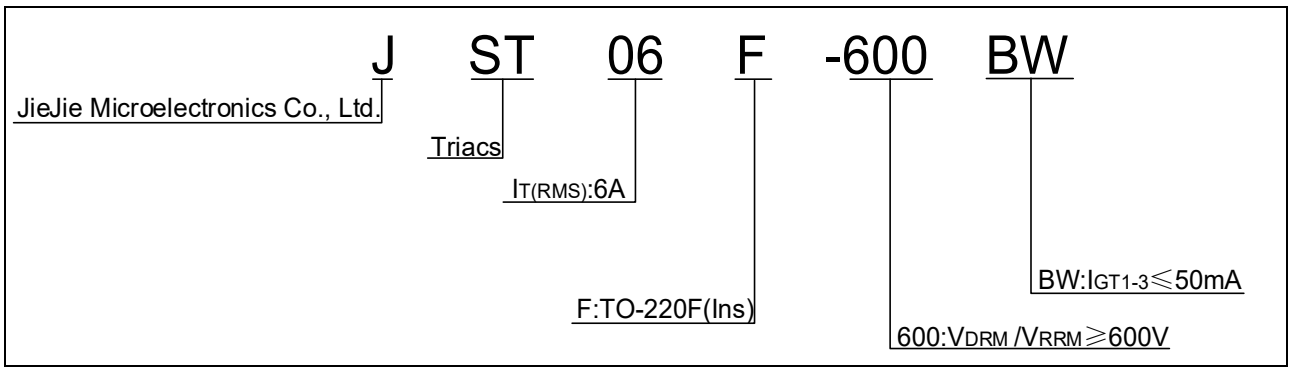
STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX.)	Unit
V_{TM}	I_{TM} =8.5A t_p=380μs	T_j=25℃	1.5	V
V_{TO}	Threshold voltage	T_j=125℃	0.82	V
R_D	Dynamic resistance	T_j=125℃	57	mΩ
I_{DRM}	V_D =V_{DRM} V_R =V_{RRM}	T_j=25℃	5	μA
I_{RRM}		T_j=125℃	0.2	mA

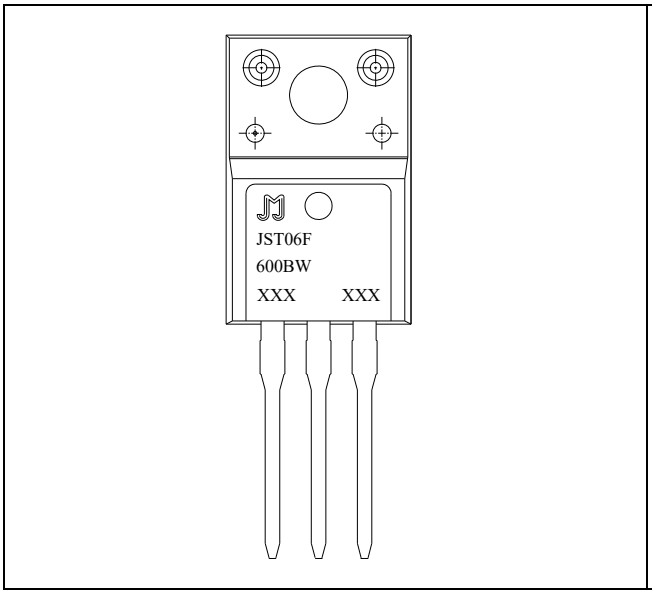
THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (AC)	3.2	℃/W
$R_{th(j-a)}$	junction to ambient (AC)	60	℃/W

ORDERING INFORMATION



MARKING



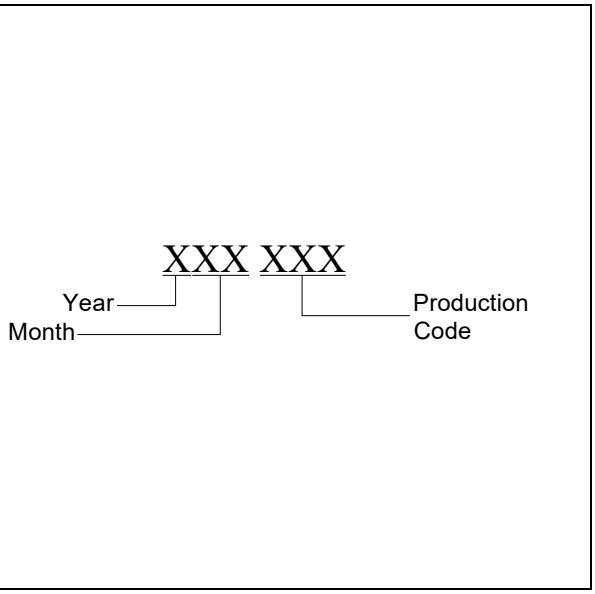


FIG.1: Maximum power dissipation versus RMS on-state current

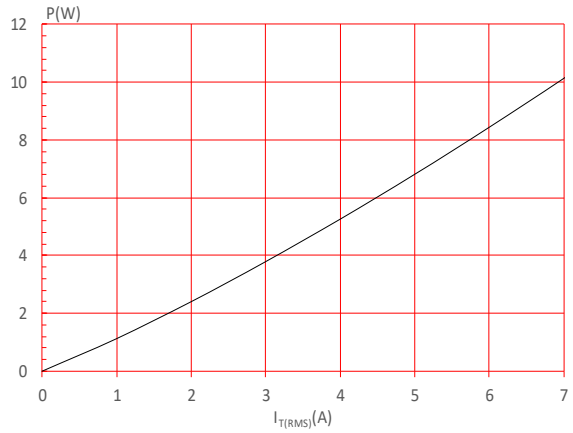


FIG.2: RMS on-state current versus case temperature

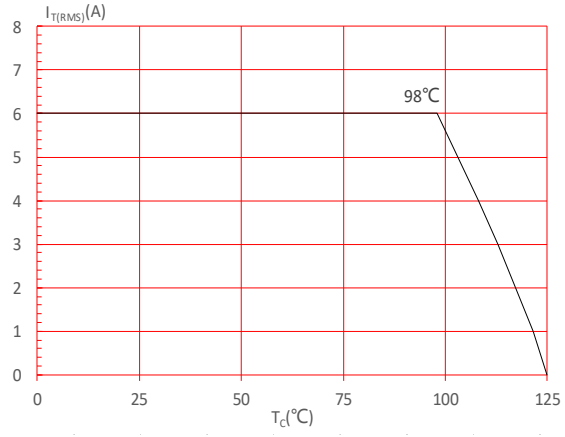


FIG.3: Surge peak on-state current versus number of cycles

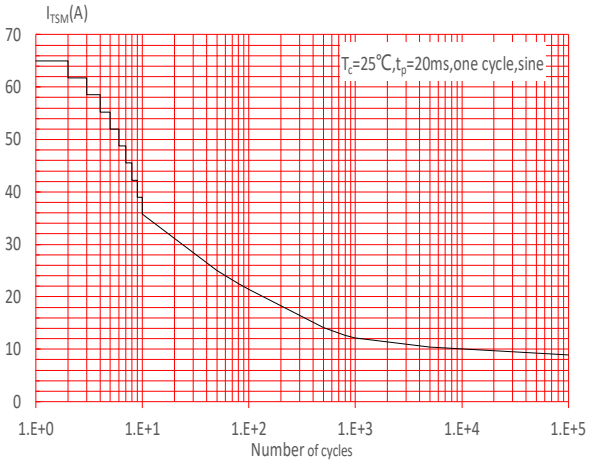


FIG.4: On-state characteristics

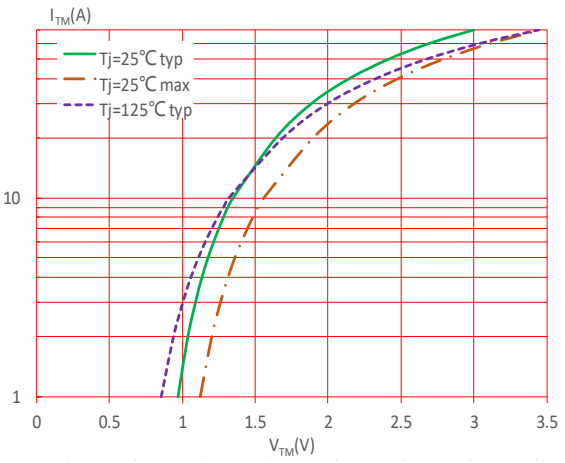


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width t_p<20ms, and corresponding value of I^2t (dI/dt<100A/μs)

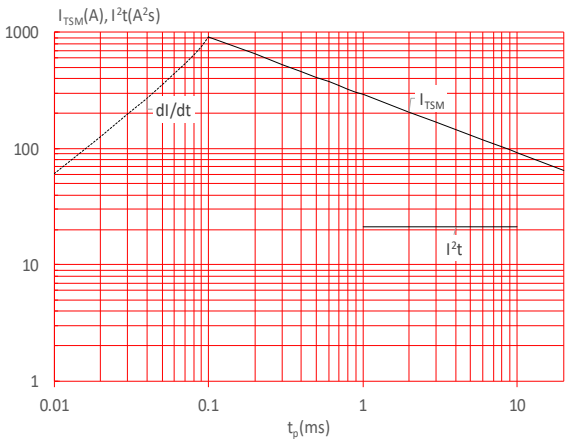


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature

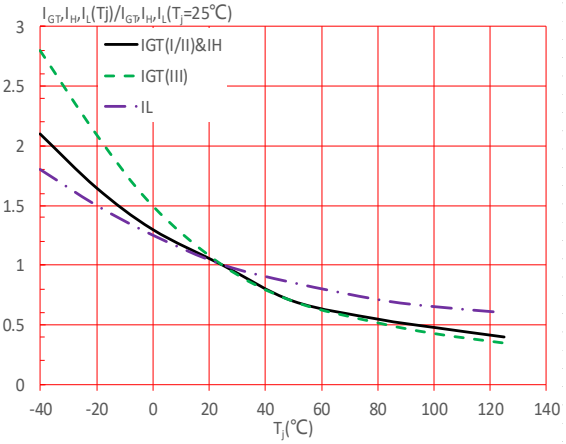
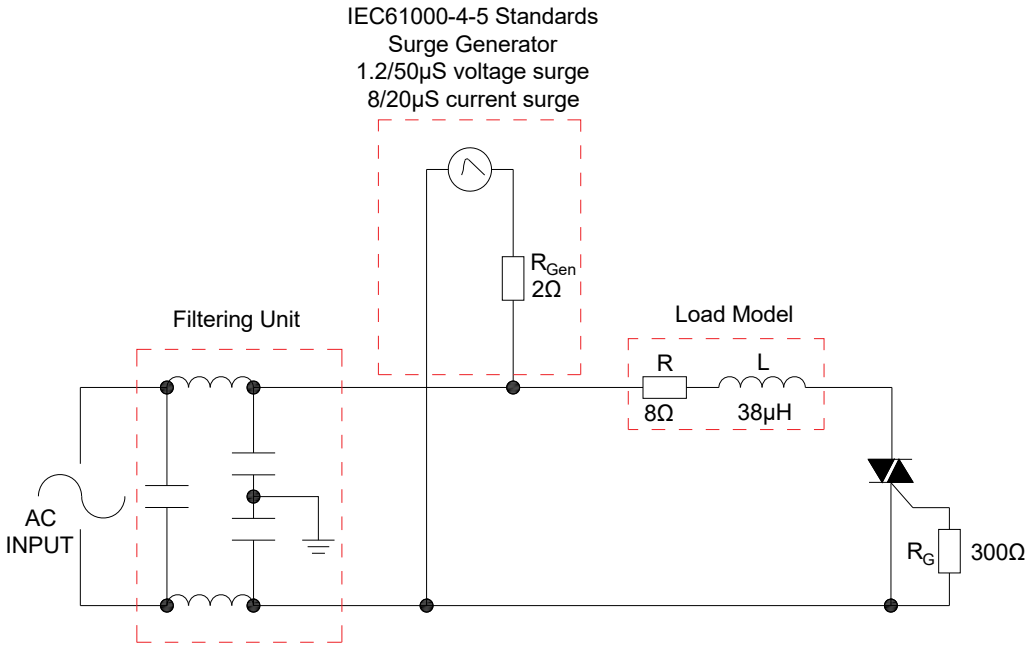


FIG.7：Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



LEAD FORMING AND SOLDERING

Refer to the application note “Assembly Instructions for Thyristors in Through-hole Package” released by JieJie Microelectronics.

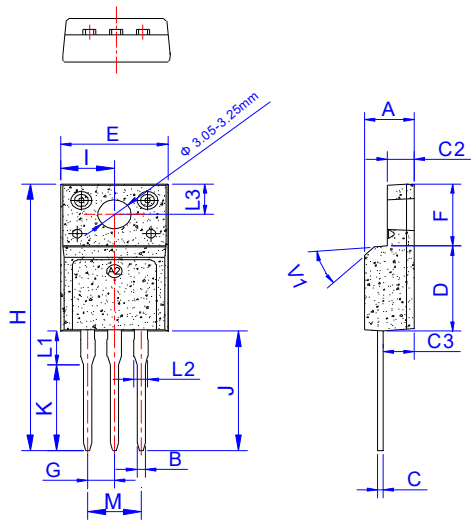
ORDERING INFORMATION

Order code	Voltage V_{DRM}/V_{RRM} (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		Ⅰ-Ⅱ-Ⅲ			
JST06F-600BW	600	50	TO-220F(Ins)	50	Tube

Document Revision History

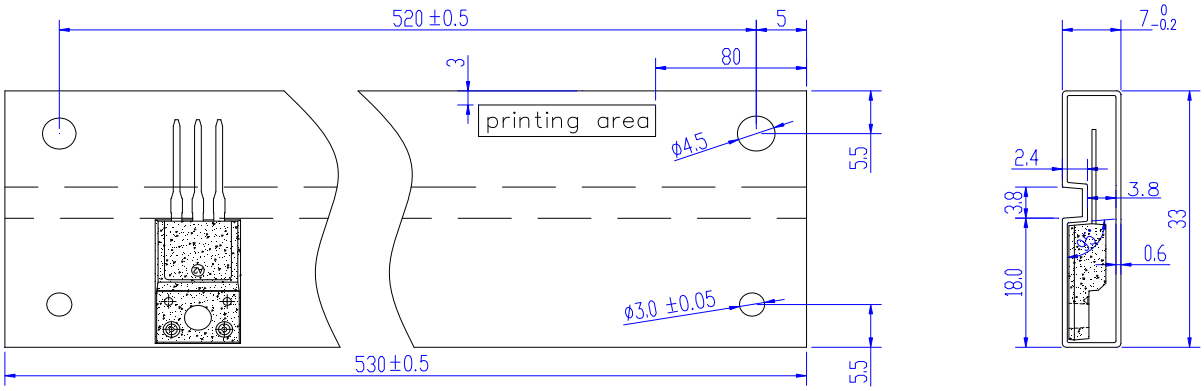
Date	Revision	Changes
Apr.11, 2023	A.1.0	Last updated
Oct.13, 2025	A.1.1	Revise PACKAGE MECHANICAL DATA

PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.50		4.90	0.177		0.193
B	0.74	0.80	0.83	0.029	0.031	0.033
C	0.47		0.65	0.019		0.026
C2	2.45		2.75	0.096		0.108
C3	2.60		3.00	0.102		0.118
D	8.80		9.30	0.346		0.366
E	9.80		10.4	0.386		0.410
F	6.40		6.80	0.252		0.268
G	2.40		2.70	0.094		0.106
H	28.0		29.8	1.102		1.173
I	4.80		5.20	0.189		0.205
J	12.60		13.00	0.496		0.512
K	9.60		10.00	0.378		0.394
L1	3.20		3.80	0.126		0.150
L2	1.14		1.70	0.045		0.067
L3	3.20		3.60	0.126		0.142
M	4.80		5.20	0.189		0.205
V1		45°			45°	

DELIVERY MODE



PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-220F	TUBE	50	1,000	5,000

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